

DC DIP Phototransistor Optocoupler

Features

- High isolation 5300 VRMS
- DC input with transistor output
- Operating temperature range 55 °C to 125 °C
- RoHS compliance
- REACH compliance
- Halogen free
- Regulatory Approvals
 - UL UL1577 (Pending Approval)
 - VDE EN60747-5-5 (Pending Approval)
 - CQC GB4943.1, GB8898 (Pending Approval)
 - IEC60065, IEC60950 (Pending Approval)

Description

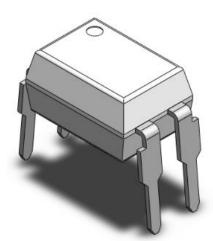
The CT521-1GB consists of a photo transistor optically coupled to a gallium arsenide Infraredemitting diode in a DIP package.

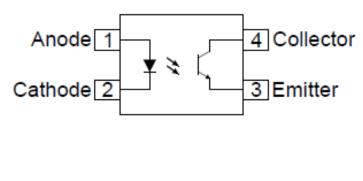
Applications

- Switch mode power supplies
- Computer peripheral interface
- Microprocessor system interface

Package Outline











Absolute Maximum Rating at 25°C

Symbol	Parameters	Ratings	Units	Notes
Viso	Isolation voltage	5300	Vrms	
Ртот	Total power dissipation	200	mW	
Topr	Operating temperature	-55 ~ +125	°C	
Тѕтс	Storage temperature	-55 ~ +150	°C	
Tsol	Soldering temperature	260	°C	
Emitter				
IF	Forward current	60	mA	
IF(TRANS)	Peak transient current (≤1µs P.W,300pps)	1000	mA	
VR	Reverse voltage	6	V	
PD	Emitter power dissipation	100	mW	
Detector				
Pc	Detector power dissipation	150	mW	
B _{VCEO}	Collector-Emitter Breakdown Voltage	80	V	
BVECO	Emitter-Collector Breakdown Voltage	7	V	
lc	Collector Current	80	mA	



Electrical Characteristics $T_A = 25^{\circ}C$ (unless otherwise specified)

Emitter Characteristics

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
VF	Forward voltage	IF=10mA	-	1.25	1.4	V	
I _R	Reverse Current	$V_R = 6V$	-	-	5	μΑ	
CIN	Input Capacitance	f= 1MHz	-	30	-	pF	

Detector Characteristics

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
BVCEO	Collector-Emitter Breakdown	I _C = 100μA	55	-	-	V	
B _{VECO}	Emitter-Collector Breakdown	I _E = 100μA	7	-	-	V	
		V _{CE} = 24V, I _F =0mA	-	-	100	nA	
ICEO	Collector-Emitter Dark Current	V _{CE} = 24V, I _F =0mA,Ta = 85°C	-	-	50	μA	

Transfer Characteristics

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
CTR	Current Transfer Ratio	IF= 5mA, V _{CE} = 5V	100	-	600	%	
CIK		I _F = 1mA, V _{CE} = 0.4V	30	-	-	%	
Variant	Collector-Emitter Saturation	IF= 1mA, Ic= 0.2mA			0.4	V	
Vce(sat)	Voltage	IF= IIIIA, IC= 0.2IIIA	-	-	0.4		
Rio	Isolation Resistance	VIO= 500VDC	5x10 ¹⁰	-	-	Ω	
C _{IO}	Isolation Capacitance	f= 1MHz	-	0.25	1	pF	

Switching Characteristics

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
tr	Rise Time		-		16		
t _f	Fall Time	Ic= 2mA, VcE= 2V	-		16	μS	
t _{on}	Turn-on time	R _L = 100Ω	-		20		
t _{off}	Turn-off time		-		20	μS	



1.8

2.0

20V

100 110

80

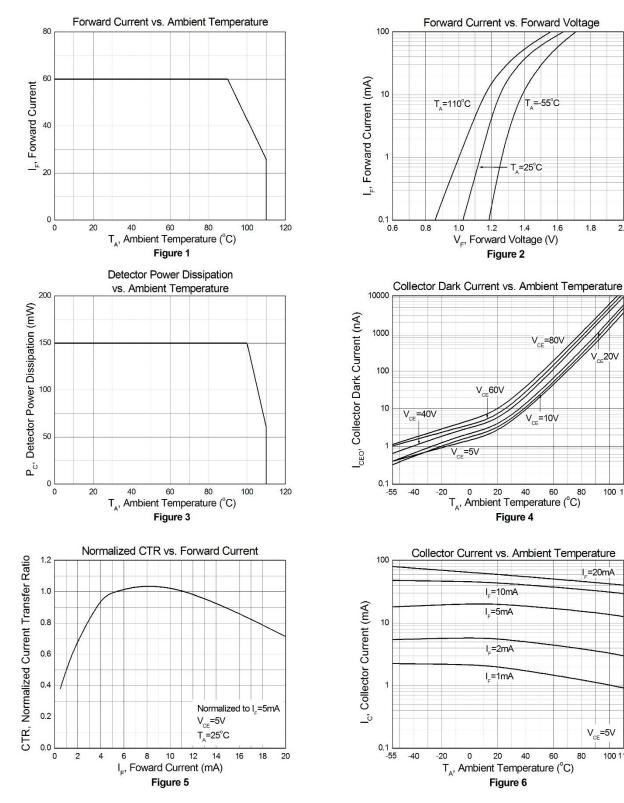
I_=20mA

V_{CF}=5V

100 110

80

Typical Characteristic Curves





CT521-1GB

P_(MAX.)

50

10

DC DIP Phototransistor Optocoupler

I_=1mA

vs. Collector Current

=2m

I_=5mA

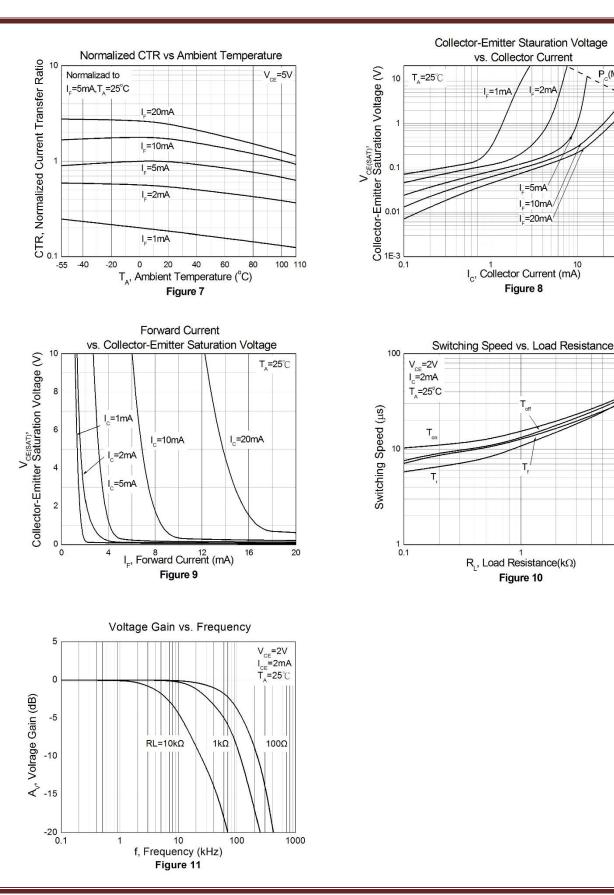
I_=10mA I_=20mA

I_c, Collector Current (mA)

Figure 8

 R_L , Load Resistance(k Ω)

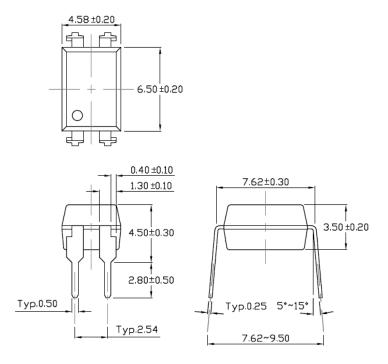
Figure 10



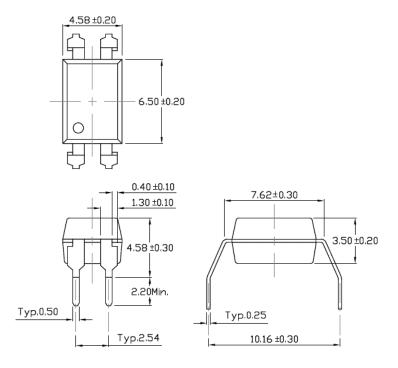


Package Dimension Dimensions in mm unless otherwise stated

Standard DIP – Through Hole

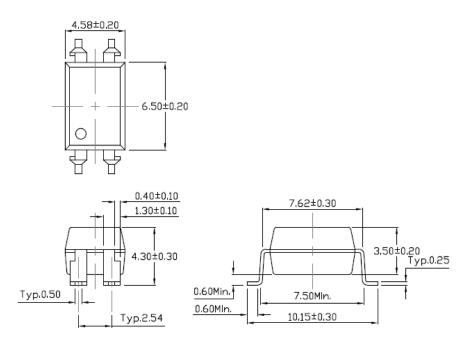


Gullwing (400mil) Lead Forming – Through Hole (M Type)

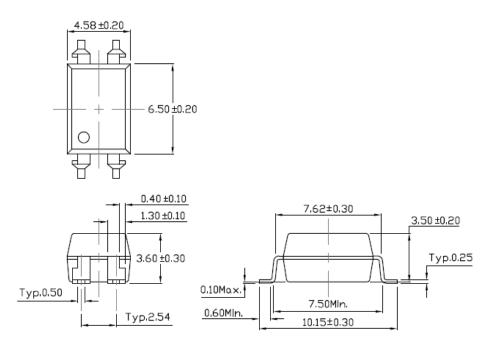




Surface Mount Lead Forming (S Type)

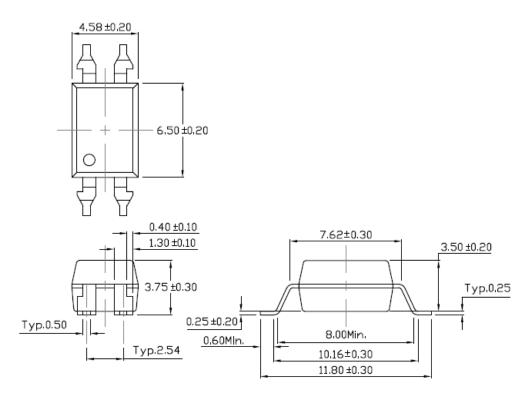


Surface Mount (Low Profile) Lead Forming (SL Type)





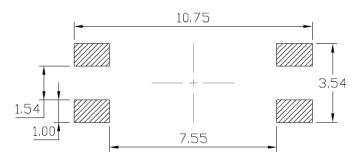
Surface Mount (Gullwing) Lead Forming (SLM Type)



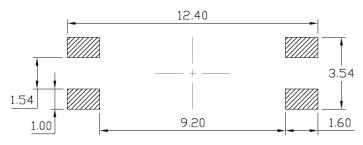


Recommended Solder Mask Dimensions in mm unless otherwise stated

Surface Mount Lead Forming & Surface Mount (Low Profile) Lead Forming



Surface Mount (Gullwing) Lead Forming



Marking Information



Note:

- CT : Denotes "CT Micro"
- 521-1 : Part Number
- GB : CTR Rank
- V : VDE Safety Option (V or none)
- Y : Fiscal Year
- WW : Work Week
- K : Manufacturing Code



Ordering Information

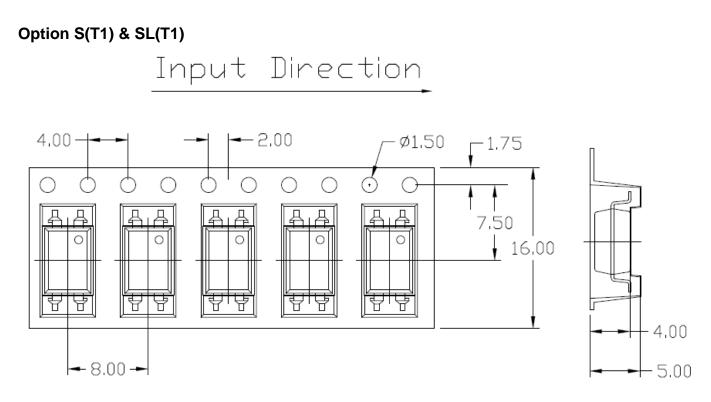
CT521-1GB(V)(W)(Y)

- CT : Denotes "CT Micro"
- 521-1 : Part Number
- GB : CTR Rank
- V : VDE Safety Option(V or none)
- W : Lead form option (S, SL, SLM, M or none)
- Y : Tape and reel option (T1, T2 or none)

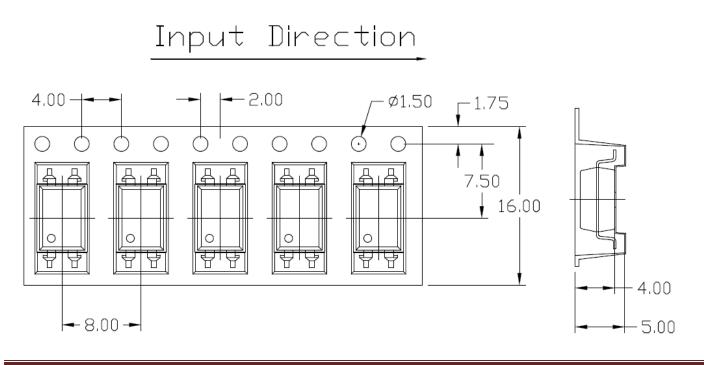
Option	Description	Quantity
None	Standard 4 Pin DIP	100 Units/Tube
М	Gullwing (400mil) Lead Forming	100 Units/Tube
S(T1)	Surface Mount Lead Forming – With Option 1 Taping	1500 Units/Reel
S(T2)	Surface Mount Lead Forming – With Option 2 Taping	1500 Units/Reel
SL(T1)	Surface Mount (Low Profile) Lead Forming- With Option 1 Taping	1500 Units/Reel
SL(T2)	Surface Mount (Low Profile) Lead Forming – With Option 2 Taping	1500 Units/Reel
SLM(T1)	Surface Mount (Gullwing) Lead Forming– With Option 1 Taping	1500 Units/Reel
SLM(T2)	Surface Mount (Gullwing) Lead Forming – With Option 2 Taping	1500 Units/Reel



Carrier Tape Specifications Dimensions in mm unless otherwise stated

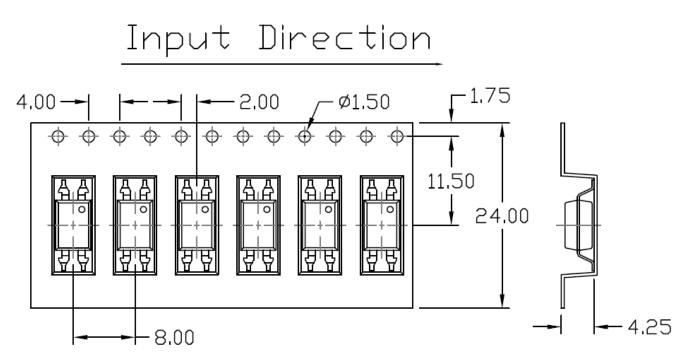


Option S(T2) & SL(T2)

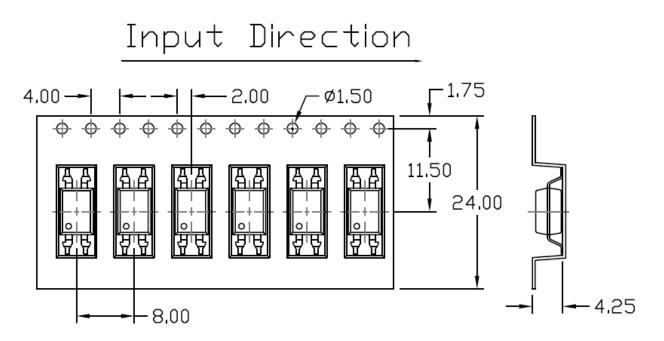




Option SLM(T1)



Option SLM(T2)





Wave soldering (JEDEC22A111 compliant)

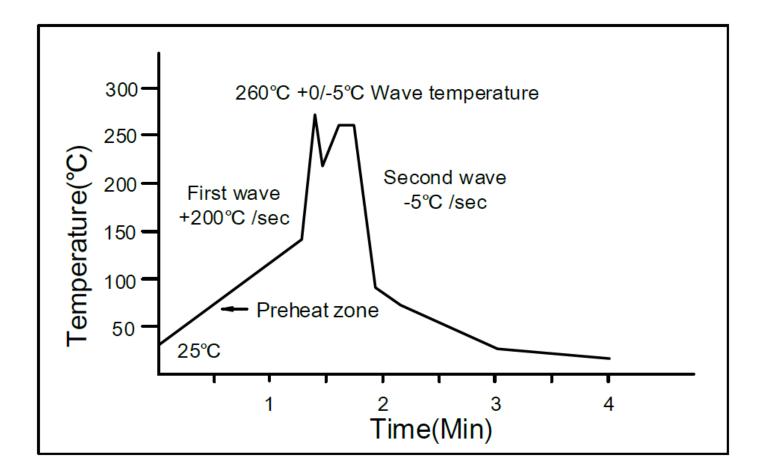
One time soldering is recommended within the condition of temperature.

Temperature: 260+0/-5°C.

Time: 10 sec.

Preheat temperature:25 to 140°C.

Preheat time: 30 to 80 sec.

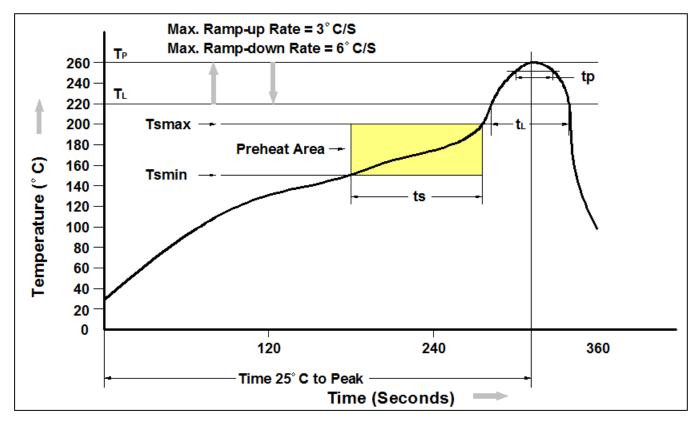


Hand soldering by soldering iron

Allow single lead soldering in every single process. One time soldering is recommended. Temperature: 350+0/-5°C Time: 3 sec max.



Reflow Profile



Profile Feature	Pb-Free Assembly Profile
Temperature Min. (Tsmin)	150°C
Temperature Max. (Tsmax)	200°C
Time (ts) from (Tsmin to Tsmax)	60-120 seconds
Ramp-up Rate (t∟ to t⊳)	3°C/second max.
Liquidous Temperature (TL)	217°C
Time (t _L) Maintained Above (T _L)	60 – 150 seconds
Peak Body Package Temperature	260°C +0°C / -5°C
Time (t _P) within 5°C of 260°C	30 seconds
Ramp-down Rate $(T_P \text{ to } T_L)$	6°C/second max
Time 25°C to Peak Temperature	8 minutes max.



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